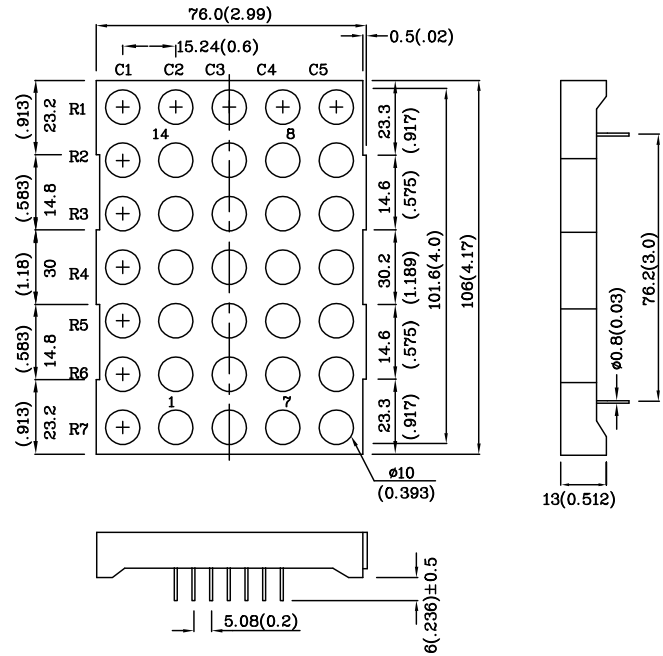
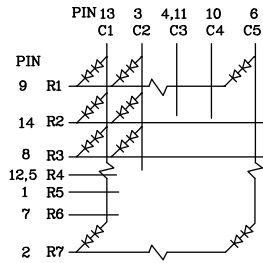


Features

- 4.0 INCH MATRIX HEIGHT.
- DOT SIZE 10mm.
- LOW CURRENT OPERATION.
- HIGH CONTRAST AND LIGHT OUTPUT.
- COMPATIBLE WITH ASCII AND EBCDIC CODES.
- STACKABLE HORIZONTALLY.
- COLUMN ANODE AVAILABLE.
- EASY MOUNTING ON P.C. BOARDS OR SOCKETS.
- MULTICOLOR AVAILABLE.
- MECHANICALLY RUGGED.
- STANDARD : GRAY FACE, WHITE DOT.
- RoHS COMPLIANT.



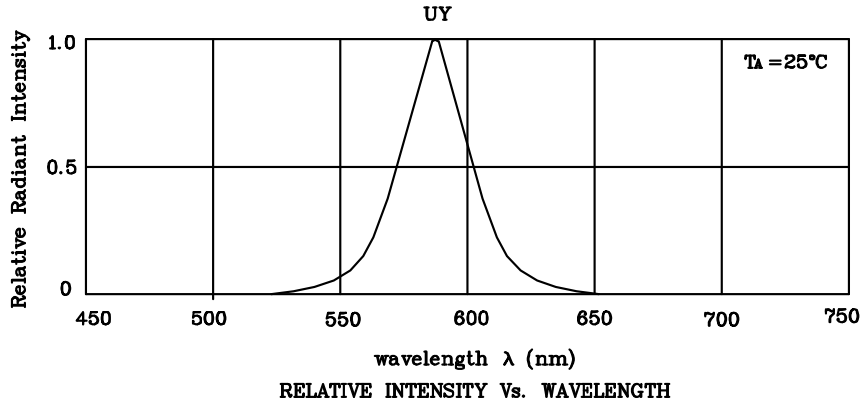
Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25(0.01)$ " unless otherwise noted.

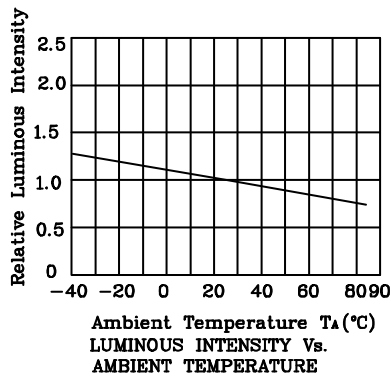
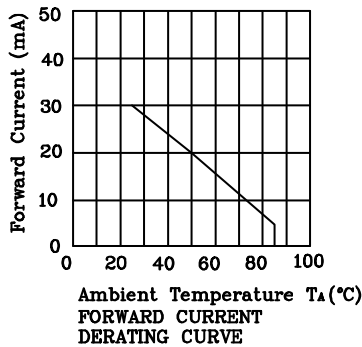
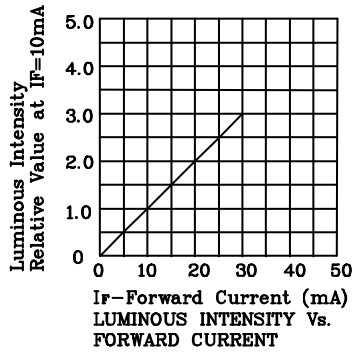
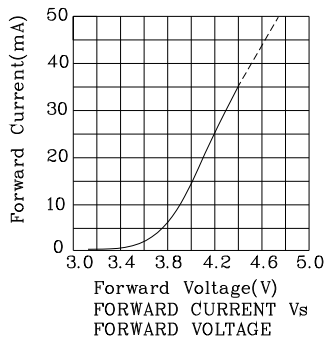
Absolute Maximum Ratings (TA=25°C)		UY (GaAsP/GaP)	Unit
Reverse Voltage Per Segment or (Dp and Comma)	VR	10	V
Forward Current Per Segment or (Dp and Comma)	IF	30	mA
Forward Current (peak) Per Segment or (Dp and Comma) 1/10Duty Cycle 0.1ms Pulse Width	iFS	140	mA
Power Dissipation Per Segment or (Dp and Comma)	PT	150	mW
Operating Temperature	TA	-40 ~ +85	°C
Storage Temperature	Tstg	-40 ~ +85	
Lead Solder Temperature [2mm below package base]	260°C For 5 Seconds		

Operating Characteristics (TA=25°C)		UY (GaAsP/GaP)	Unit
Forward Voltage (typ.) Per Segment or (Dp and Comma) (IF=10mA)	VF	3.9	V
Forward Voltage (max.) Per Segment or (Dp and Comma) (IF=10mA)	VF	5.0	V
Reverse Current (VR=10V)	IR	10	uA
Wavelength of Peak Emission (IF=10mA)	λP	590	nm
Wavelength of Dominant Emission (IF=10mA)	λD	588	nm
Spectral Line Full Width At Half-Maximum (IF=10mA)	$\Delta\lambda$	35	nm
Capacitance (VF=0V, f=1MHz)	C	20	pF

Part Number	Emitting Color	Emitting Material	Luminous Intensity (IF=10mA) ucd		Wavelength nm λP	Description
			min.	typ.		
XMUY100A	Yellow	GaAsP/GaP	1900	7990	590	Column Anode



❖ UY



Wave Soldering Profile For Lead-free Through-hole LED.



NOTES:

- 1.Recommend the wave temperature 245°C~260°C.The maximum soldering temperature should be less than 260°C.
- 2.Do not apply stress on epoxy resins when temperature is over 85 degree°C.
- 3.The soldering profile apply to the lead free soldering (Sn/Cu/Ag alloy).
- 4.No more than once.

Remarks:

If special sorting is required (e.g. binning based on forward voltage, luminous intensity, or wavelength), the typical accuracy of the sorting process is as follows:

1. Wavelength: +/-1nm
2. Luminous Intensity: +/-15%
3. Forward Voltage: +/-0.1V

Note: Accuracy may depend on the sorting parameters.